

## High power NPN epitaxial planar bipolar transistor

#### **Features**

- High breakdown voltage V<sub>CEO</sub> = 250 V
- Complementary to 2STA2120
- Typical f<sub>t</sub> = 25 MHz
- Fully characterized at 125 °C

### **Application**

■ Audio power amplifier

#### **Description**

The device is a NPN transistor manufactured using new BiT-LA (Bipolar transistor for linear amplifier) technology. The resulting transistor shows good gain linearity behaviour. solete Productle

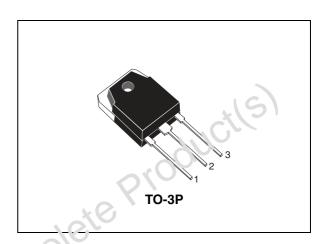


Figure 1. Internal schematic diagram

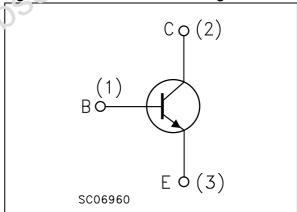


Table 1. **Device summary** 

Order code	Marking	Package	Packaging
2STC5948	2STC5948	TO-3P	Tube

Electrical ratings 2STC5948

# 1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-base voltage (I <sub>E</sub> = 0)	250	V
$V_{CEO}$	Collector-emitter voltage (I <sub>B</sub> = 0)	250	V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	6	V
I <sub>C</sub>	Collector current	17	Α
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5 ms)	34	Α
P <sub>TOT</sub>	Total dissipation at T <sub>c</sub> = 25 °C	200	W
T <sub>stg</sub>	Storage temperature	-65 to 150	် ပ
$T_J$	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	R	Value	Unit
R <sub>thj-case</sub>	Thermal resistance junction-case	n a	0.625	°C/W
	aduci(s) obs	n.al	0.625	°C/W
	R <sub>thj-case</sub>	R <sub>thj-case</sub> Thermal resistance junction-case	R <sub>thj-case</sub> Thermal resistance junction-case n. a.	R <sub>thj-case</sub> Thermal resistance junction-case r. a. 0.625

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### 2 Electrical characteristics

 $(T_{case} = 25 \, ^{\circ}C; \text{ unless otherwise specified})$ 

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current (I <sub>E</sub> = 0)	V <sub>CB</sub> = 250 V			5	μΑ
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 6 V			5	μΑ
V <sub>(BR)CEO</sub> <sup>(1)</sup>	Collector-emitter breakdown voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 50 mA	250		1/9	V
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage (I <sub>F</sub> = 0)	I <sub>C</sub> = 100 μA	250	UC		V
V <sub>(BR)EBO</sub> (1)	Emitter-base breakdown voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = 1 mA	g			V
I Vac\''	Collector-emitter saturation voltage	I <sub>C</sub> = 8 A I <sub>B</sub> = 870 mA			3	V
V <sub>BE</sub> <sup>(1)</sup>	Base-emitter voltage	$I_C = 7 \text{ A}$ $V_{CE} = 5 \text{ V}$			1.5	V
h <sub>FE</sub>	DC current gain	$I_C = 1 \land V_{CE} = 5 \lor V_{CE}$	80 35		160	
f <sub>T</sub>	Transition frequency	I <sub>C</sub> = 1 A V <sub>CE</sub> = 5 V		25		MHz

<sup>1.</sup> Pulsed duration = 300 μs, duty εyclε ≤ 1.5%

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Electrical characteristics 2STC5948

# 2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Derating curve

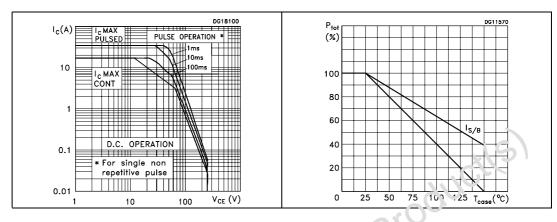


Figure 4. Output characteristics

Figure 5. Document gain

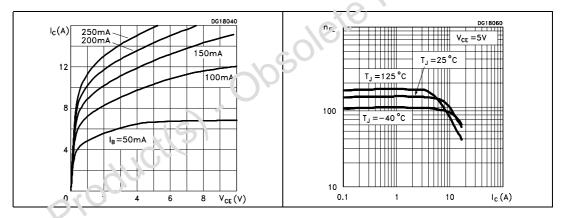
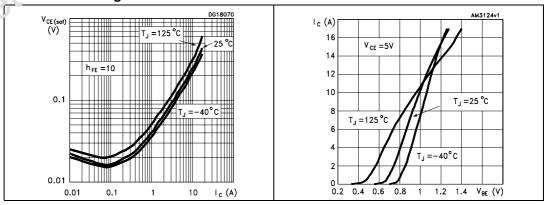


Figure 3. Collector-emitter saturation voltage

Figure 7. Base-emitter voltage



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### 3 Package mechanical data

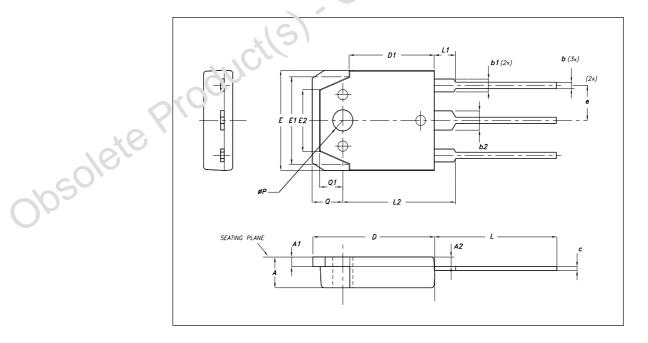
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Obsolete Product(s).

TO-3P	Mec	hanical	data

DIM	mm.			
DIM.	MIN.	TYP	MAX.	
Α	4.6		5	
A1	1.45	1.50	1.65	
A2	1.20	1.40	1.60	
b	0.80	1	1.20	
b1	1.80		2.20	
b2	2.80		3.20	
С	0.55	0.60	0.75	
D	19.70	19.90	20.1	
D1		13.90	11/2	
E	15.40		15.80	
E1		13.60		
E2		9.60	1/-	
е	5.15	5.45	5.75	
L	19.50	20	20.50	
L1		3 50		
L2	18.20	17.40	18.60	
Р	3.10		3.30	
Q	_	5		
Q1		3.80		



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2STC5948 Revision history

# 4 Revision history

Table 5. Document revision history

Date	Revision	Changes
26-Nov-2007	1	Initial release.
06-May-2008	2	New graphics
11-Jul-2008	3	Updated Figure 7.
17-Nov-2008	4	Content reworked to improve readability, no technical changes

Obsolete Products)

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